# Surface Mount Schottky Power Rectifier

# POWERMITE<sup>®</sup> Power Surface Mount Package

The Schottky Powermite employs the Schottky Barrier principle with a barrier metal and epitaxial construction that produces optimal forward voltage drop-reverse current tradeoff. The advanced packaging techniques provide for a highly efficient micro miniature, space saving surface mount Rectifier. With its unique heatsink design, the Powermite has the same thermal performance as the SMA while being 50% smaller in footprint area, and delivering one of the lowest height profiles, < 1.1 mm in the industry. Because of its small size, it is ideal for use in portable and battery powered products such as cellular and cordless phones, chargers, notebook computers, printers, PDAs and PCMCIA cards. Typical applications are ac/dc and dc-dc converters, reverse battery protection, and "Oring" of multiple supply voltages and any other application where performance and size are critical.

### Features:

- Low Profile Maximum Height of 1.1 mm
- Small Footprint Footprint Area of 8.45 mm2
- Low VF Provides Higher Efficiency and Extends Battery Life
- Supplied in 12 mm Tape and Reel
- Low Thermal Resistance with Direct Thermal Path of Die on Exposed Cathode Heat Sink

### **Mechanical Characteristics:**

- Powermite is JEDEC Registered as DO-216AA
- Case: Molded Epoxy
- Epoxy Meets UL94V-0 at 1/8"
- Weight: 62 mg (approximately)
- Device Marking: BCV
- Lead and Mounting Surface Temperature for Soldering Purposes. 260°C Maximum for 10 Seconds

#### **MAXIMUM RATINGS**

Please See the Table on the Following Page



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SCHOTTKY BARRIER RECTIFIER 1.0 AMPERES 20 VOLTS



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POWERMITE CASE 457 PLASTIC

## MARKING DIAGRAM



BCV = Device Code M = Date Code

## **ORDERING INFORMATION**

Device	Package	Shipping
MBRM120ET1	POWERMITE	3000/Tape & Reel
MBRM120ET3	POWERMITE	12,000/Tape & Reel



#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	20	V
Average Rectified Forward Current (At Rated $V_R$ , $T_C = 130^{\circ}C$ )	IO	1.0	А
Peak Repetitive Forward Current (At Rated V <sub>R</sub> , Square Wave, 20 kHz, $T_C = 135^{\circ}C$ )	IFRM	2.0	A
Non–Repetitive Peak Surge Current (Non–Repetitive peak surge current, halfwave, single phase, 60 Hz)	IFSM	50	A
Storage Temperature	T <sub>stg</sub>	-65 to 150	°C
Operating Junction Temperature	Тј	-65 to 150	°C
Voltage Rate of Change (Rated V <sub>R</sub> , T <sub>J</sub> = 25°C)	dv/dt	10,000	V/μs
HERMAL CHARACTERISTICS			
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Thermal Resistance – Junction-to-Lead (Anode) (Note 1)	R <sub>til</sub>	35	°C/W
Thermal Resistance – Junction–to–Tab (Cathode) (Note 1)	R <sub>titab</sub>	23	
Thermal Resistance – Junction-to-Ambient (Note 1)	Ŕ <sub>tja</sub>	277	

1. Mounted with minimum recommended pad size, PC Board FR4, See Figures 9 and 10.

# **ELECTRICAL CHARACTERISTICS**

Maximum Instantaneous Forward Voltage (Note 2), See Figure 2	VF	TJ = 25°C	T <sub>J</sub> = 100°C	V
$(I_F = 0.1 \text{ A})$ $(I_F = 1.0 \text{ A})$ $(I_F = 2.0 \text{ A})$		0.455 0.530 0.595	0.360 0.455 0.540	
Maximum Instantaneous Reverse Current (Note 2), See Figure 4	I <sub>R</sub>	TJ = 25°C	T <sub>J</sub> = 100°C	μΑ
(V <sub>R</sub> = 20 V) (V <sub>R</sub> = 10 V) (V <sub>R</sub> = 5.0 V)		10 1.0 0.5	1600 500 300	

2. Pulse Test: Pulse Width  $\leq$  250 µs, Duty Cycle  $\leq$  2%.

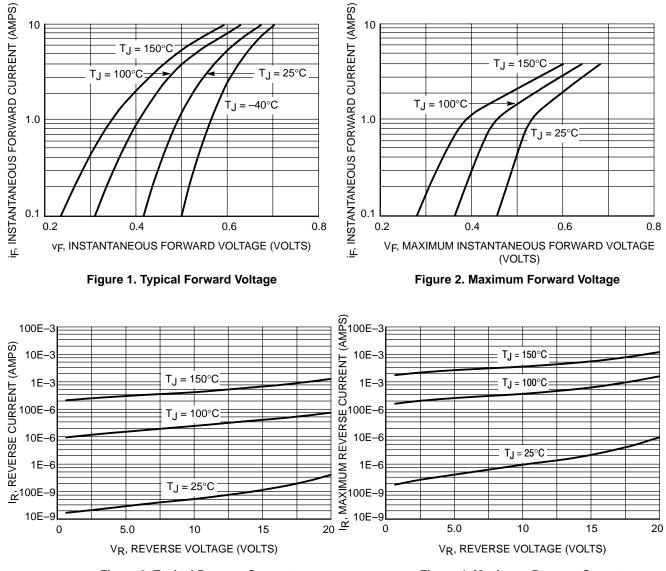
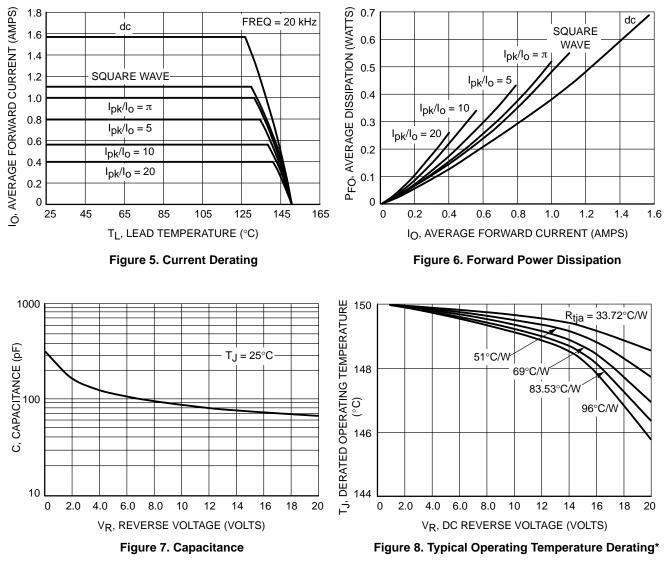




Figure 4. Maximum Reverse Current



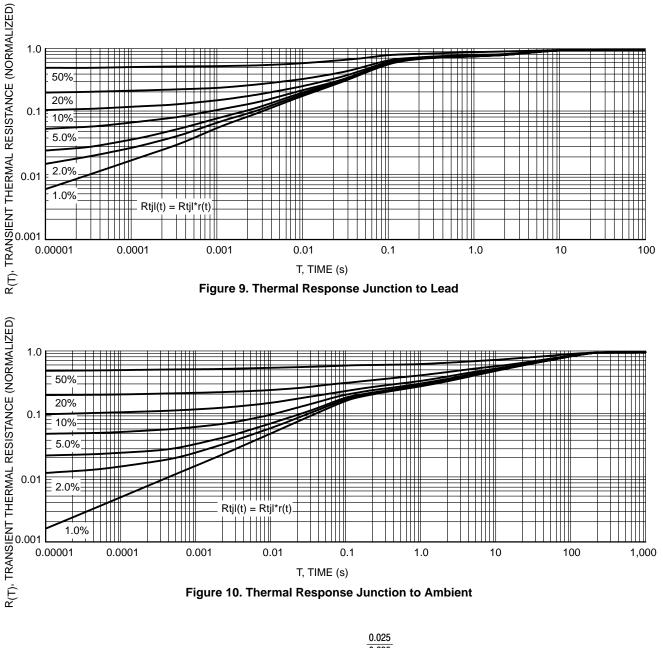
\* Reverse power dissipation and the possibility of thermal runaway must be considered when operating this device under any reverse voltage conditions. Calculations of T<sub>J</sub> therefore must include forward and reverse power effects. The allowable operating T<sub>J</sub> may be calculated from the equation:  $T_J = T_{Jmax} - r(t)(Pf + Pr)$  where

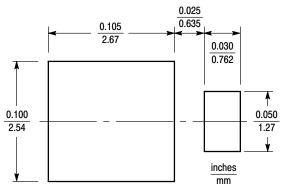
r(t) = thermal impedance under given conditions,

Pf = forward power dissipation, and

Pr = reverse power dissipation

This graph displays the derated allowable T<sub>J</sub> due to reverse bias under DC conditions only and is calculated as  $T_J = T_{Jmax} - r(t)Pr$ , where r(t) = Rthja. For other power applications further calculations must be performed.

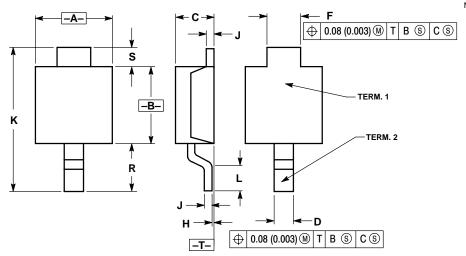




Minimum Recommended Footprint

# PACKAGE DIMENSIONS

POWERMITE PLASTIC PACKAGE CASE 457-04 ISSUE D



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER. 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	1.75	2.05	0.069	0.081
В	1.75	2.18	0.069	0.086
C	0.85	1.15	0.033	0.045
D	0.40	0.69	0.016	0.027
F	0.70	1.00	0.028	0.039
н	-0.05	+0.10	-0.002	+0.004
J	0.10	0.25	0.004	0.010
K	3.60	3.90	0.142	0.154
L	0.50	0.80	0.020	0.031
R			0.047	0.059
S			0.019 REF	

# <u>Notes</u>

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